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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/765,072	01/28/2004	Jianmin Qiao	248157US77DIV	9478
22850	7590 11/01/2005		EXAMINER	
OBLON, SPIVAK, MCCLELLAND, MAIER & NEUSTADT, P.C. 1940 DUKE STREET			SCHILLINGER, LAURA M	
	IA, VA 22314		ART UNIT	PAPER NUMBER
	<b>,</b>		2813	

DATE MAILED: 11/01/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)				
	10/765,072	QIAO, JIANMIN				
Office Action Summary	Examiner	Art Unit				
	Laura M. Schillinger	2813				
The MAILING DATE of this communication a Period for Reply	ppears on the cover sheet with	the correspondence address				
A SHORTENED STATUTORY PERIOD FOR REF WHICHEVER IS LONGER, FROM THE MAILING  - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory perions for reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the main earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNICA 1.136(a). In no event, however, may a reply od will apply and will expire SIX (6) MONTH: ute, cause the application to become ABAN	TION.  y be timely filed  S from the mailing date of this communication.  DONED (35 U.S.C. § 133).				
Status						
1) Responsive to communication(s) filed on 11	August 2005.					
2a)⊠ This action is <b>FINAL</b> . 2b)□ Th	This action is FINAL. 2b) ☐ This action is non-final.					
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the practice under	r <i>Ex parte Quayle</i> , 1935 C.D. 1	1, 453 O.G. 213.				
Disposition of Claims						
4) Claim(s) 11,12,14,15 and 17 is/are pending	in the application.					
4a) Of the above claim(s) 12,14,15 and 17 is	/are withdrawn from considera	tion.				
5) Claim(s) is/are allowed.						
6)⊠ Claim(s) <u>11</u> is/are rejected.						
7) Claim(s) is/are objected to.	llan alaatian naariinamaant					
8) Claim(s) are subject to restriction and	i/or election requirement.					
Application Papers						
9) The specification is objected to by the Exami	ner.					
10)☐ The drawing(s) filed on is/are: a)☐ a						
Applicant may not request that any objection to the						
Replacement drawing sheet(s) including the corre						
11) ☐ The oath or declaration is objected to by the	Examiner. Note the attached C	office Action of form PTO-152.				
Priority under 35 U.S.C. § 119						
12) ☐ Acknowledgment is made of a claim for foreignal All b) ☐ Some * c) ☐ None of:	gn priority under 35 U.S.C. § 1	19(a)-(d) or (f).				
1. Certified copies of the priority documents have been received.						
2. Certified copies of the priority docume						
3. Copies of the certified copies of the pr		ceived in this National Stage				
application from the International Bure		anivad				
* See the attached detailed Office action for a li	st of the centiled copies not re	ceiveu.				
Attachment(s)	<b></b>	(070, 440)				
<ol> <li>Notice of References Cited (PTO-892)</li> <li>Notice of Draftsperson's Patent Drawing Review (PTO-948)</li> </ol>	Paper No(s)/N	nmary (PTO-413) Mail Date				
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date	5) Notice of Info 6) Other:	rmal Patent Application (PTO-152)				

Art Unit: 2813

#### **DETAILED ACTION**

## Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claim 11 is rejected under 35 U.S.C. 102(e) as being anticipated by Blosse et al ('512)

The applied reference has a common inventor with the instant application. Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 102(e) might be overcome either by a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not the invention "by another," or by an appropriate showing under 37 CFR 1.131.

11. A method comprising selectively etching a trench dielectric layer and a contact dielectric layer in a structure comprising the trench dielectric layer, the contact dielectric layer, and an etch stop layer therebetween comprising undoped silicon oxide and having a hole therein, the hole containing a trench dielectric layer material, with an etch gas including C<sub>2</sub>H<sub>2</sub>F<sub>4</sub> (Abs., lines: 1-20 and Col.7, lines: 40-45 and Col.4-5, lines: 54-35).

### Response to Arguments

Applicant's arguments filed 8/11/05 have been fully considered but they are not persuasive. Applicant argues that the claim language implicitly requires that the trench dielectric is deposited after forming a hole in the etch stop layer. However, the Examiner disagrees with the assertion that such a step is implicitly required. Furthermore, claim language should be explicit, not implicit. Moreover, Applicant argues that Blosse fails to teach a hole in the etch stop layer containing a trench dielectric layer material. However, Applicant's arguments are not found to be persuasive, because the hole would contain the trench dielectric material on the inside walls of the hole. Therefore, Applicant's arguments fail to overcome the prior art rejection.

### Conclusion

THIS ACTION IS MADE FINAL. Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Laura M. Schillinger whose telephone number is (571) 272-1697. The examiner can normally be reached on M-T, R-F 7:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Carl W. Whitehead, Jr. can be reached on (571) 272-1702. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

10/25/05

Laura M Schillinger Primary Examiner Art Unit 2813